Media Management for High Density NAND Flash Memories

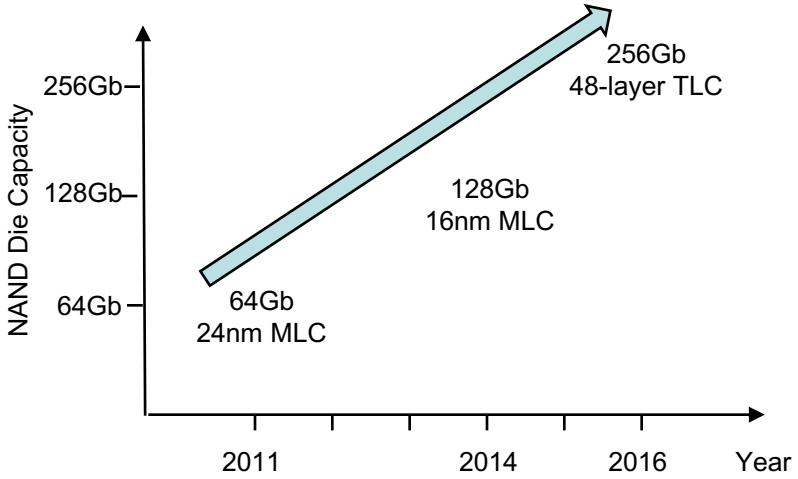
Erich F. Haratsch

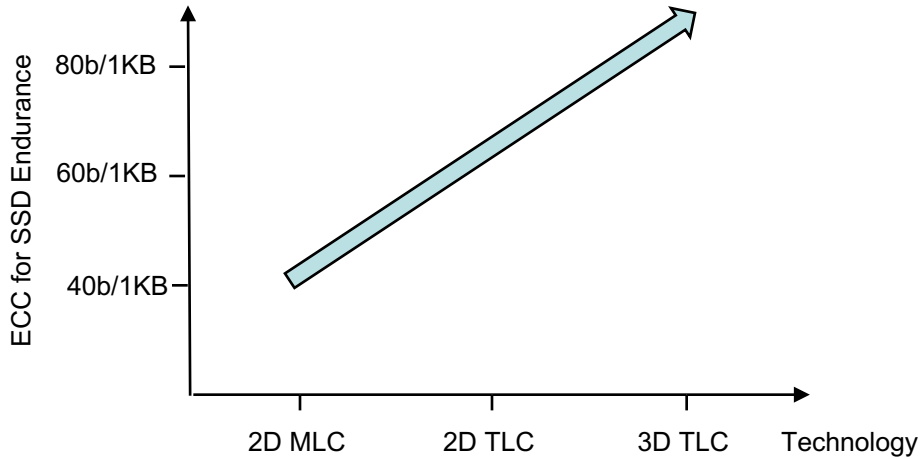
Seagate

Outline

- NAND Flash Scaling Trends
- LDPC with Hard and Soft Decision Decoding
- Adaptive Code Rates
- Read Voltage Calibration
- Redundant Silicon Elements
- Summary

NAND Scaling Trends





- 3D NAND may extend beyond 100 layers
- 3D NAND extends scaling towards 1Tb die capacity

- Required ECC for SSD-grade endurance exceeds 60b/1KB for 2D TLC
- 3D NAND relies on strong ECC to make TLC mainstream for SSDs

NAND Impairments

Impairment	Effect	Mitigation
Program/Erase Cycling	Voltage shift/widening	ECC Read Voltage Calibration
Retention	Voltage shift/widening	ECC Read Voltage Calibration
Media Defects	Page, block, plane, die failure	Redundant Silicon Elements

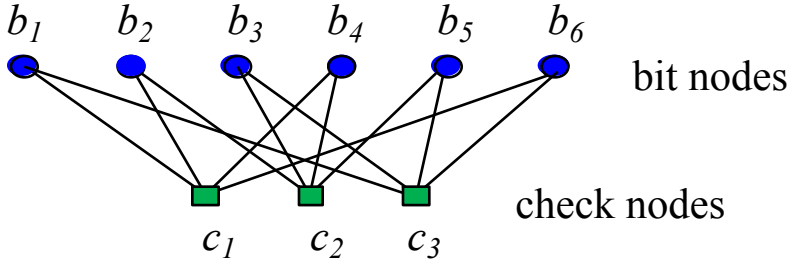
- Presented Flash media management algorithms can help to mitigate Read Disturb and Intercell Interference as well

Low-Density Parity Check (LDPC) Codes

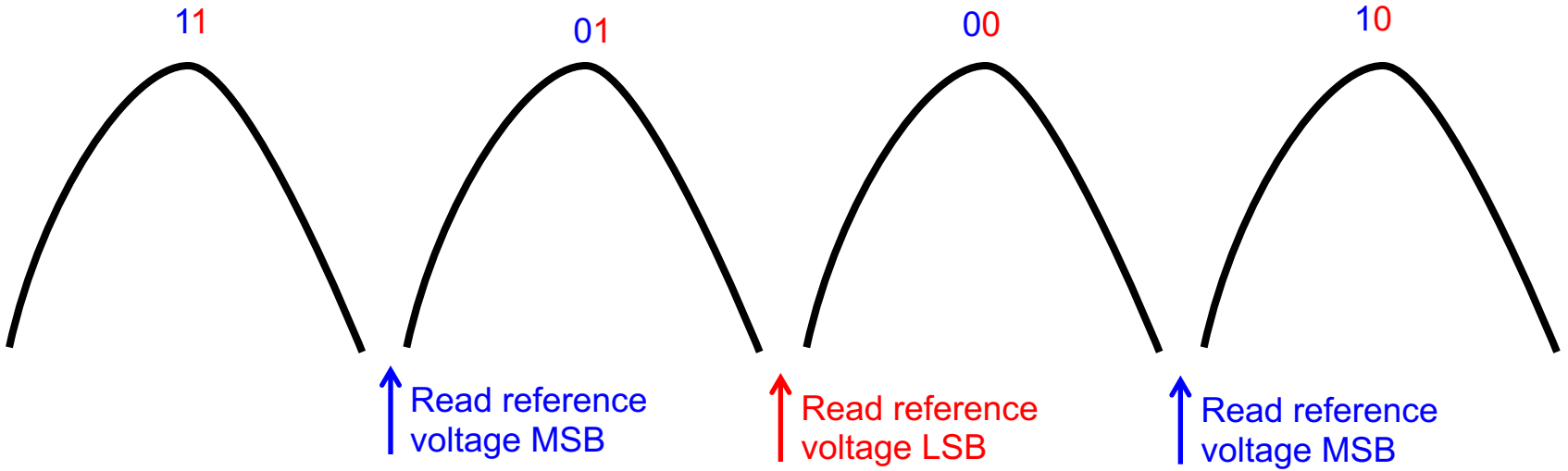
- Defined by a sparse (low density) parity check matrix H
- Are represented with a bi-partite graph
- Support hard and soft decision decoding

$$H = \begin{array}{c} \begin{matrix} b_1 & b_2 & b_3 & b_4 & b_5 & b_6 \end{matrix} \\ \begin{bmatrix} 1 & 1 & 0 & 1 & 0 & 1 \\ 0 & 1 & 1 & 1 & 1 & 0 \\ 1 & 0 & 1 & 0 & 1 & 1 \end{bmatrix} \end{array} \begin{matrix} c_1 \\ c_2 \\ c_3 \end{matrix}$$

Bi-Partite Graph:

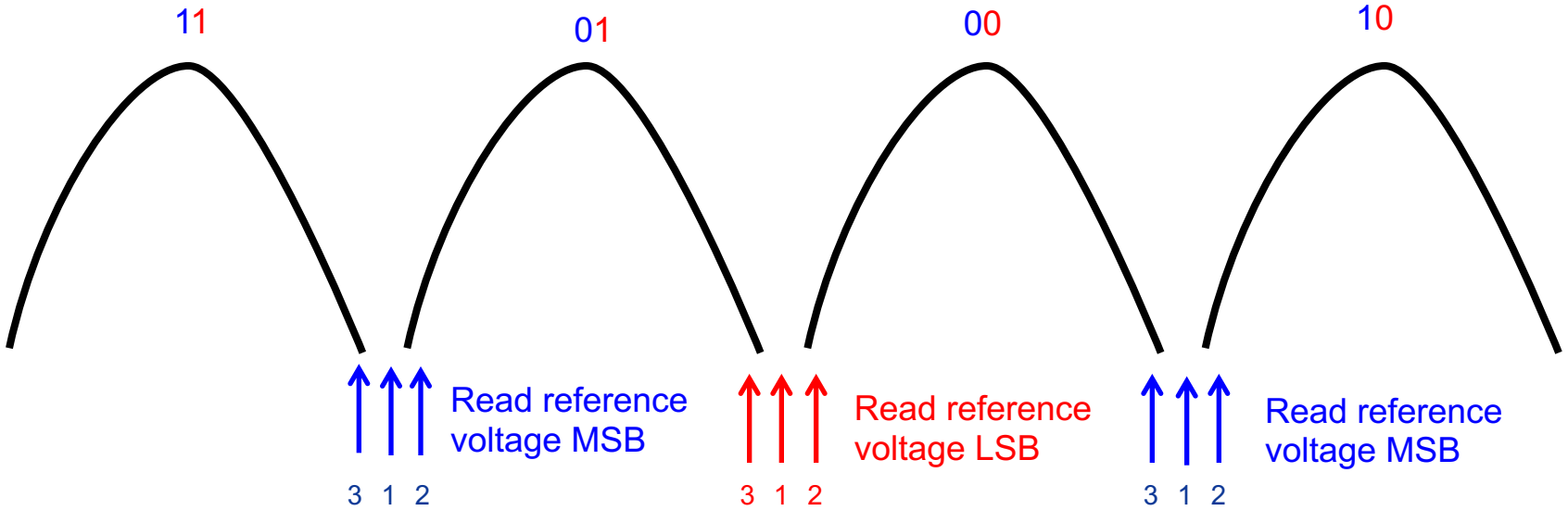


Reading from Flash: Hard Decision Decoding



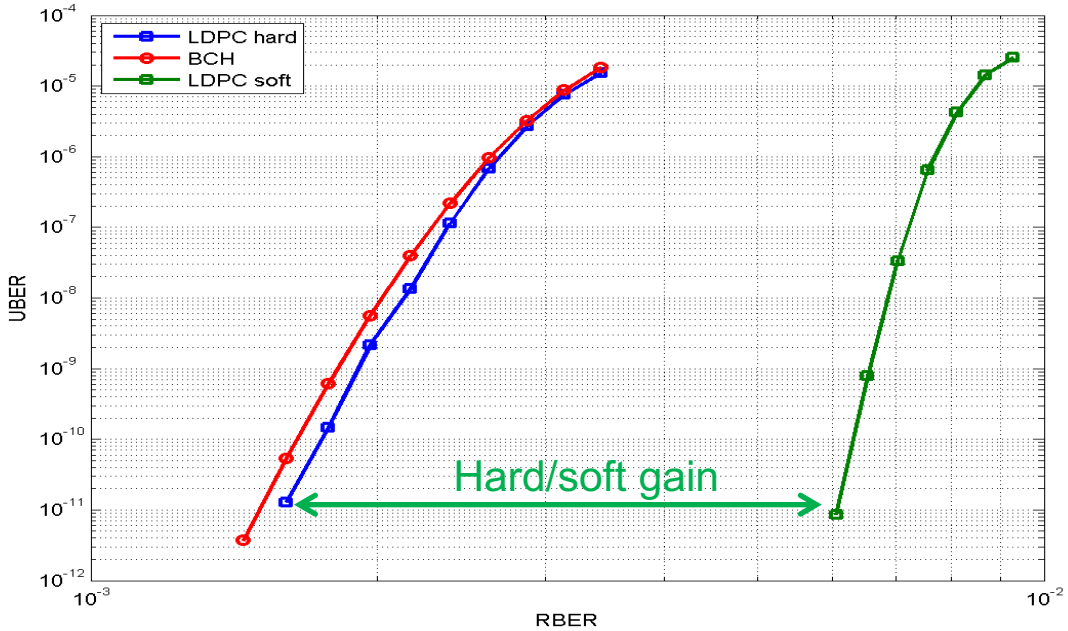
- NAND Flash Memory compares read voltage with read reference voltage to generate hard decision
- One reference voltage for LSB page, 2 reference voltages for MSB page
- Hard decision is used for decoding

Soft Decision Decoding



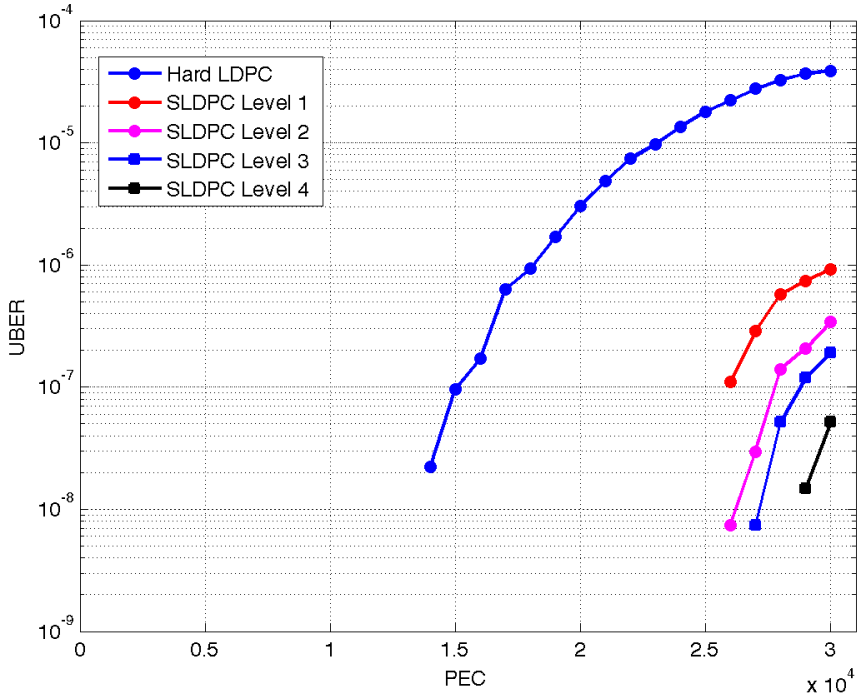
- Sequence of read operations with different read reference voltages to generate soft decision
- Computation of soft information (LLRs) based on multiple read decisions
- LDPC decoder uses soft decision during error recovery

Hard/Soft LDPC vs. BCH



- Soft-decision LDPC decoding has significantly better error correction than BCH decoding

Experimental Benefit of Soft LDPC



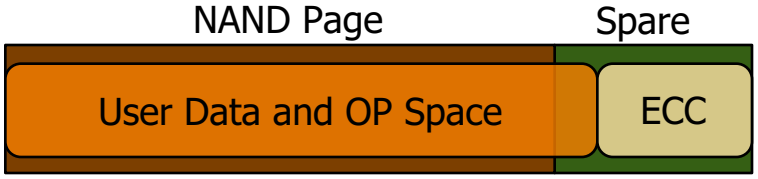
- Measured with controller silicon and firmware for 15/16nm MLC flash
- Significant error rate improvement with soft LDPC decoding

Adaptive Code Rates

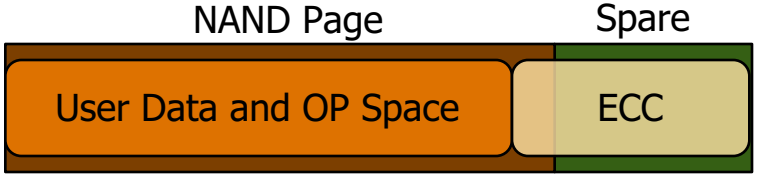
- Beginning of Life: use less ECC to increase overprovisioning
- End of life: increase ECC to maintain reliability

Conventional Error Correction:
Stores fixed ECC in spare field

Adaptive ECC (BOL):
Stores ECC in a portion of spare field and increase OP

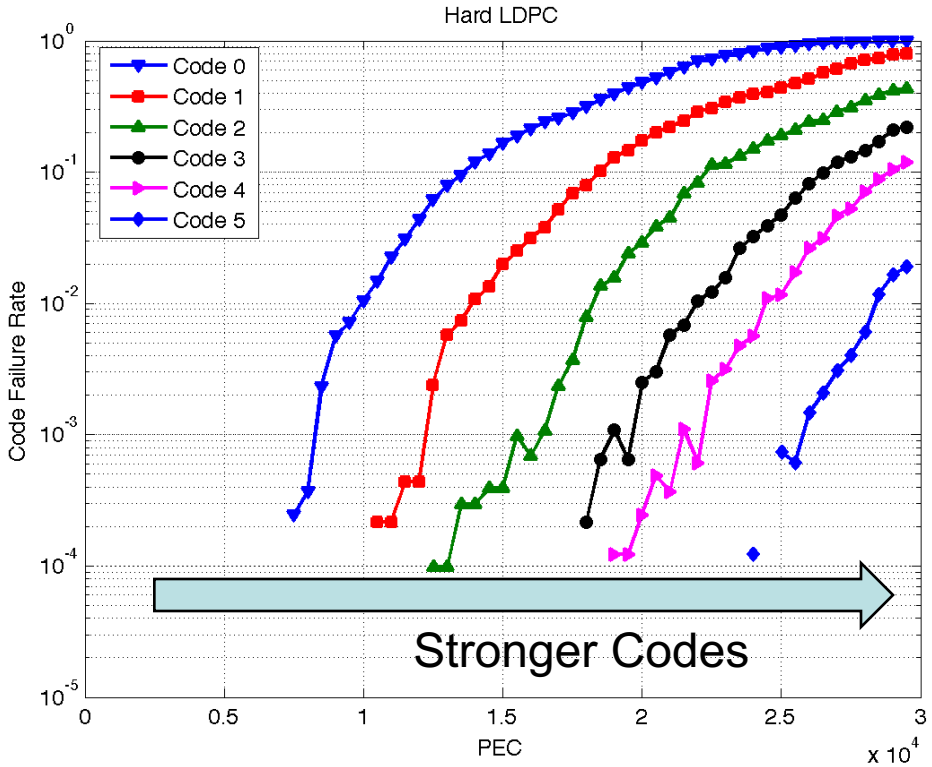


Adaptive ECC (EOL):
Stores ECC in spare field and uses some of the NAND page



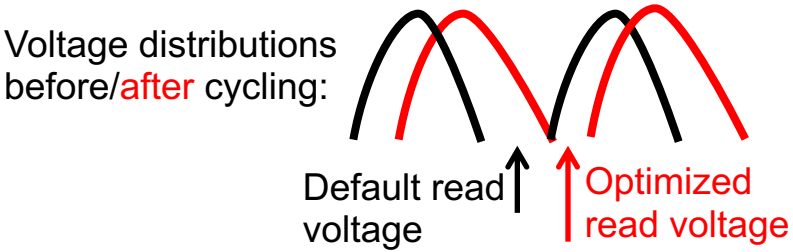
Adaptive ECC allows for more free space @ BOL = More OP and less write amplification

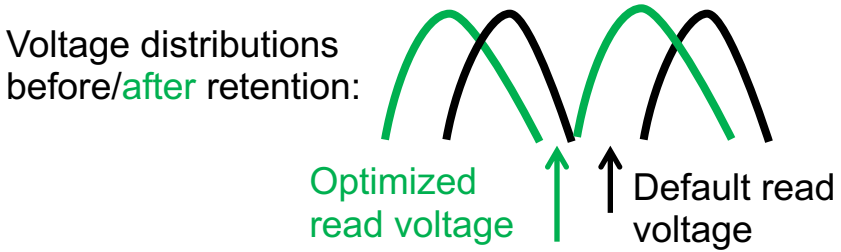
Switching Code Rates



- Measured with controller silicon and firmware for 15/16nm MLC flash
- Multiple LDPC codes cover wide RBER range
- As NAND flash ages, controller switches to the next stronger code
- Read performance improves, since stronger LDPC codes decode data faster

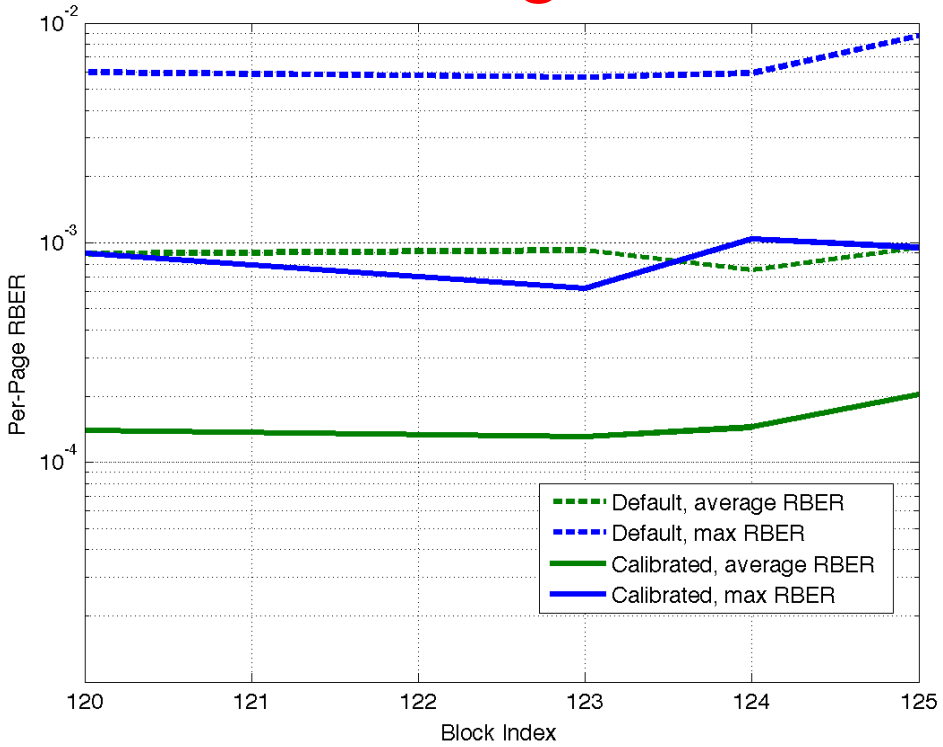
Read Voltage Calibration





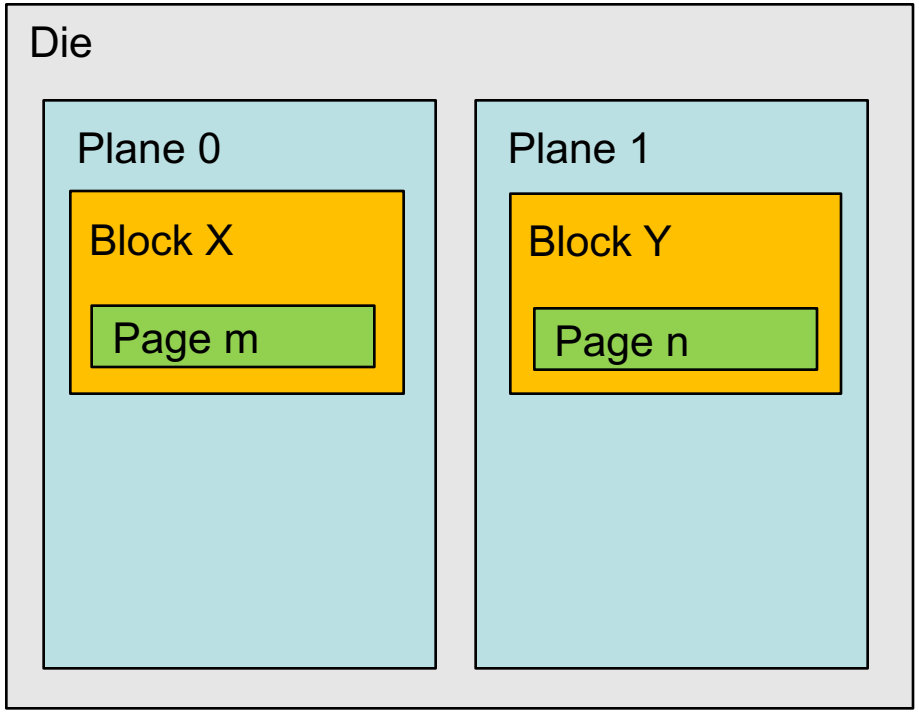
- Optimum read voltages shift as a function of endurance, retention and read disturb
- Optimized read voltages reduce retry rate and extend endurance

Experimental Results: Read Voltage Calibration



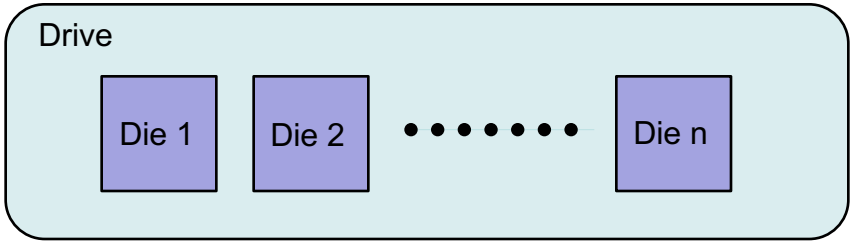
- Measured with controller silicon and firmware for 3D flash
- Significant improvement in RBER after read voltage calibration

Media Failures



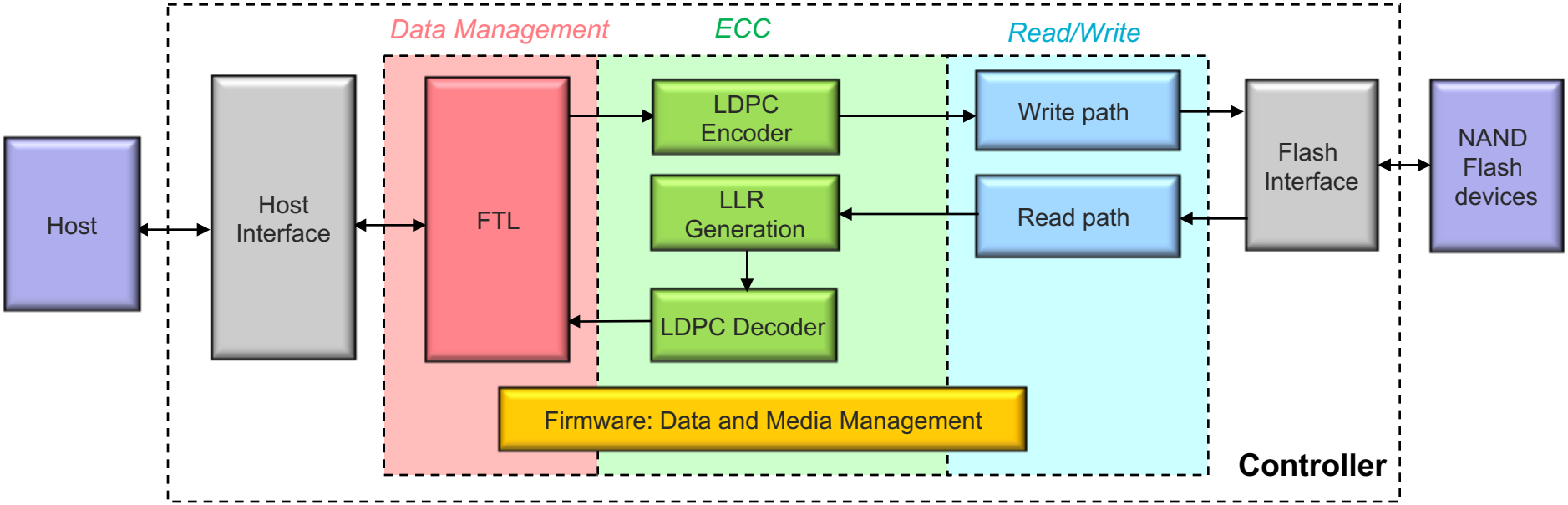
- Pages, blocks, planes or the whole die can fail
- ECC cannot recover data from such catastrophic failures
- Need RAID-like protection inside SSD

RAISE™: Redundant Array of Independent Silicon Elements



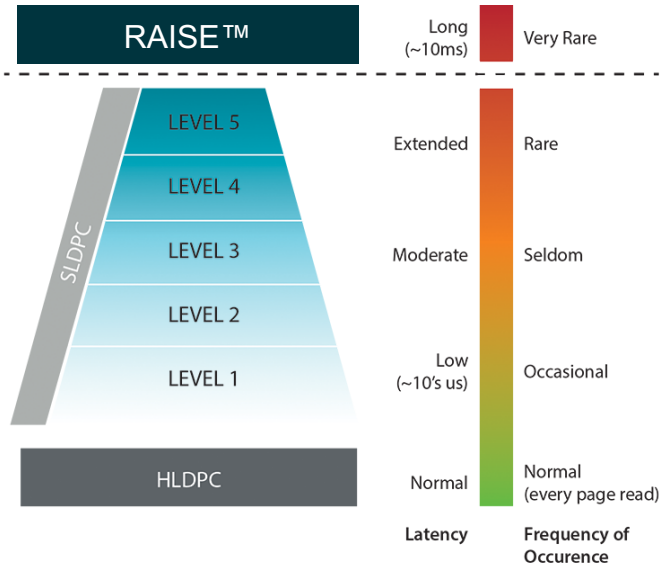
- RAID-like data protection within the drive
- Write data across multiple dies with additional protection
- Corrects full page, block or die failures when all soft LDPC steps fail

SSD Controller: Block Diagram



Multi-Level Error Correction

- Hard-decision LDPC decoding is on-the-fly error correction method
- Progressively apply stronger decoding methods such as soft-decision LDPC decoding and signal processing
- Specialized noise handling techniques for P/E cycling, retention, read disturb, etc.
- Optimize time-to-data



Conclusion

- Latest memory geometries demand intelligent NAND management features
- 3D NAND will still rely on strong ECC and advanced NAND management features to make TLC mainstream for SSD applications

Thank You! Questions?

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